

FEATURES

- ◆ Metal silicon junction,majority carrier conduction
- ◆ For surface mounted applications
- ◆ Low power loss,high efficiency
- ◆ High forward surge current capability
- ◆ For use in low voltage,high frequency inverters, free-wheeling, and polarity protection applications

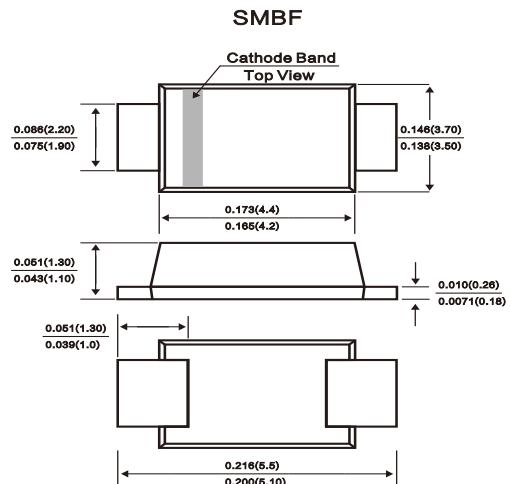
MECHANICAL DATA

Case: JEDEC SMBF molded plastic body

Terminals: leads solderable per MIL-STD-750, Method 2026

Mounting Position: Any

Weight: 57mg/0.002oz



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

| MDD Catalog Number | SYMBOLS | SS32BF | SS34BF | SS36BF | SS38BF | SS310BF | SS315BF | SS320BF | UNITS |
|---|-------------------|--------|--------|-------------|--------|---------|---------|---------|-------|
| Maximum repetitive peak reverse voltage | V _{RRM} | 20 | 40 | 60 | 80 | 100 | 150 | 200 | VOLTS |
| Maximum RMS voltage | V _{RMS} | 14 | 28 | 42 | 56 | 70 | 105 | 140 | VOLTS |
| Maximum DC blocking voltage | V _{DC} | 20 | 40 | 60 | 80 | 100 | 150 | 200 | VOLTS |
| Maximum average forward rectified current at T _L (see fig.1) | I _(AV) | | | | | 3.0 | | | Amp |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I _{FSM} | | 80.0 | | | 70.0 | | | Amps |
| Maximum instantaneous forward voltage at 3.0A | V _F | 0.55 | 0.70 | | 0.85 | | 0.95 | | Volts |
| Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =100°C | I _R | 0.5 | 5.0 | | 0.3 | 3.0 | | | mA |
| Typical junction capacitance (NOTE 1) | C _J | 450 | | | 400 | | | | pF |
| Typical thermal resistance (NOTE 2) | R _{θJA} | | | 50.0 | | | | | °C/W |
| Operating junction temperature range | T _J | | | -50 to +125 | | | | | °C |
| Storage temperature range | T _{STG} | | | -50 to +150 | | | | | °C |

Note: 1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas

Fig.1 Forward Current Derating Curve

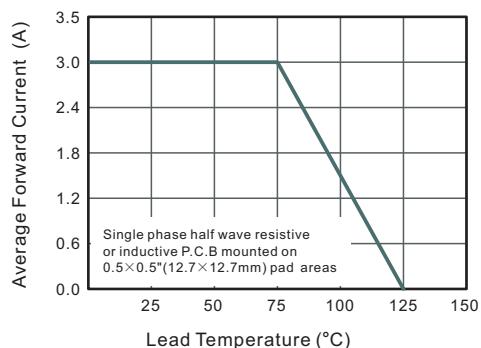


Fig.2 Typical Reverse Characteristics

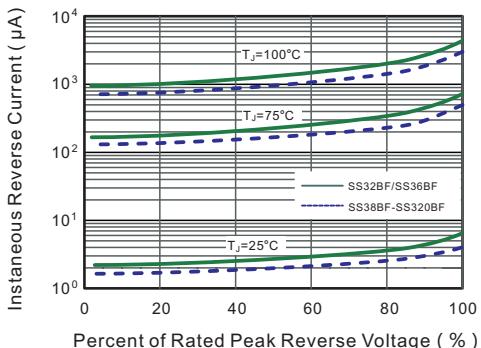


Fig.3 Typical Forward Characteristic

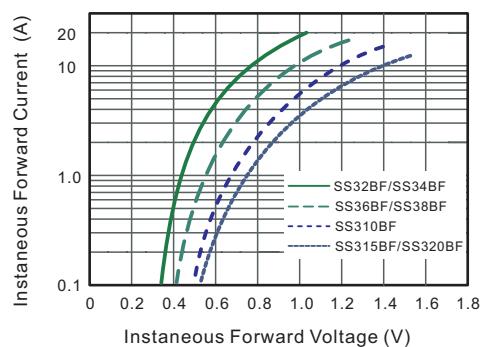


Fig.4 Typical Junction Capacitance

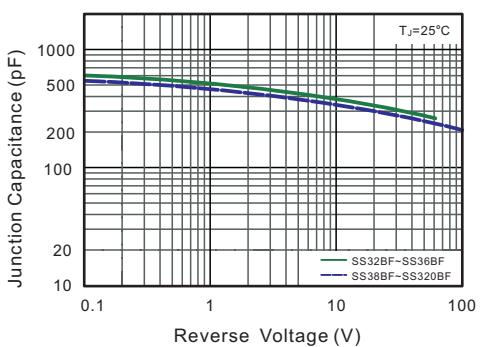


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

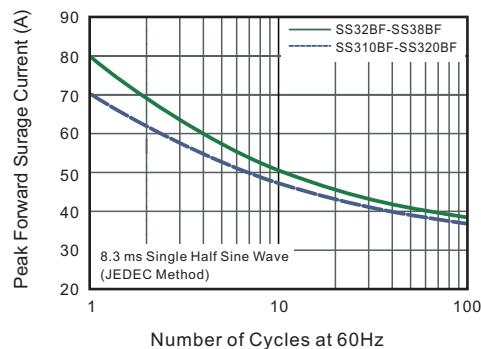
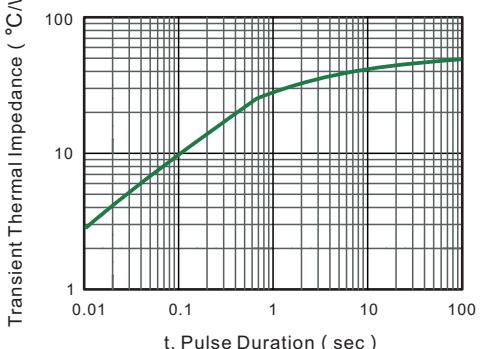


Fig.6- Typical Transient Thermal Impedance





UMW SS32BF THRU SS320BF

20V-200V 3.0A

ORDERING INFORMATION

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Youtai manufacturer:

Other Similar products are found below :

[MA4E2039](#) [MA4E2508M-1112](#) [MBR0530L-TP](#) [MBR10100CT-BP](#) [MBR1545CT](#) [MMBD301M3T5G](#) [RB160M-50TR](#)
[BAS16E6433HTMA1](#) [BAS 3010S-02LRH E6327](#) [BAT 54-02LRH E6327](#) [IDL02G65C5XUMA1](#) [NSR05F40QNXT5G](#) [NSVR05F40NXT5G](#)
[NTE555](#) [JANS1N6640](#) [SB07-03C-TB-H](#) [SK310-T](#) [SK33A-TP](#) [SK34B-TP](#) [SS3003CH-TL-E](#) [PDS3100Q-7](#) [GA01SHT18](#)
[CRS10I30A\(TE85L,QM](#) [MA4E2501L-1290](#) [MBRB30H30CT-1G](#) [JANTX1N5712-1](#) [SB007-03C-TB-E](#) [SK33B-TP](#) [SK35A-TP](#) [SK38B-LTP](#)
[NTE505](#) [NTSB30U100CT-1G](#) [VS-6CWQ10FNHM3](#) [CRG04\(T5L,TEMQ\)](#) [ACDBA1100LR-HF](#) [ACDBA1200-HF](#) [ACDBA240-HF](#)
[ACDBA3100-HF](#) [CDBQC0530L-HF](#) [ACDBA260LR-HF](#) [ACDBA1100-HF](#) [MA4E2502L-1246](#) [10BQ015-M3/5BT](#) [10BQ060-M3/5BT](#)
[NRVB130LSFT1G](#) [CRS08TE85LQM](#) [PMAD1108-LF](#) [B120Q-13-F](#) [1N5819T-G](#) [B0530WSQ-7-F](#)